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CMOS 4-bit
1-chip MICROCOMPUTER

S-1340AF/13L40AF

The S-1340AF/13L40AF 4-bit microcomputer integrates 8-bit programmable timer, watch dog timer, carry output circuit, etc., on one chip. As it can be driven by batteries, this microcomputer is ideal for various compact portable equipment.
In particular, S-13L40AF, which is a low-voltage operation version of S-1340AF, is designed to be driven by one battery (1.5 V).

■ Feature

- Si gate CMOS process
- Low power consumption
- Single power supply : 1.8 V min.(for S-1340AF, 500 KHz)
  1.2 V min.(for S-13L40AF, 500 KHz)
- High-speed operation : 500 KHz max.
- ROM: 512×8 bits
- RAM: 16×4 bits
- 6 input lines and 6 output lines
- 2 timers: 8-bit programmable timer and delay timer
- Watch dog timer
- Interrupt function
- Standby function (STOP, HALT)
- Instruction execution time: 8 μ SEC /Inst min. (at 500 KHz)
- Instructions: 79 types (114 including addressing modes)
  5-level subroutine nesting
- 20-pin SOP (terminal distance: 1.27 mm)

■ Applications

- Infrared remote controller
- Compact portable equipment, others

■ Dimensions (20-pin SOP)

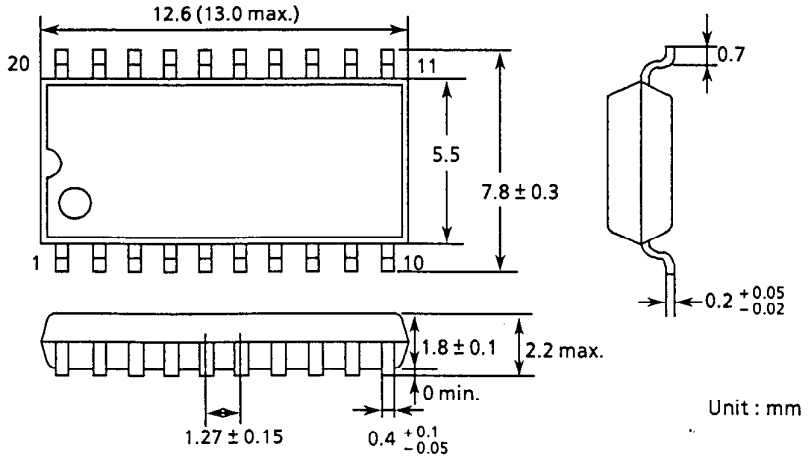

Figure 1

■ Pin Assignments

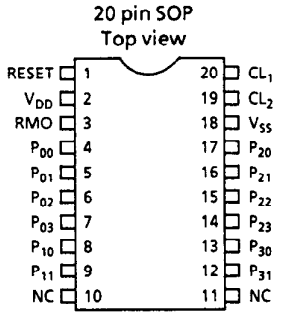

Figure 2

■ Terminal Functions

Table 1

Name	I/O	Functions
V_{DD}	—	Positive power terminal
V_{SS}	—	GND potential terminal
RESET	Input	Reset input terminal (Schmitt trigger input) Active level can be selected with mask option · Active low: with pull-up resistor · Active high: with pull-down resistor
CL_1 CL_2	I/O	Ceramic oscillator connection terminal
RMO	Output	Carrier output temrinal
P_{00} to P_{03}	Output	Output port (Nch open drain output and CMOS output can be selected with mask option)
P_{10} to P_{11}	Output	Output port (Nch open drain output and CMOS output can be selected with mask option)
P_{20} to P_{23}	Input	Input port (pull-up resistor can be built in with mask option)
P_{30} to P_{31}	Input	Input port (pull-up resistor can be built in with mask option)
N.C	—	Leave open

■ Block Diagram

S-1340/13L40AF is connected by 4-bit data bus (DB), 12-bit address bus (AB), control signals, etc., and controls the memories (ROM, RAM), registers, I/O ports, logic circuits (ALU), timers, etc.

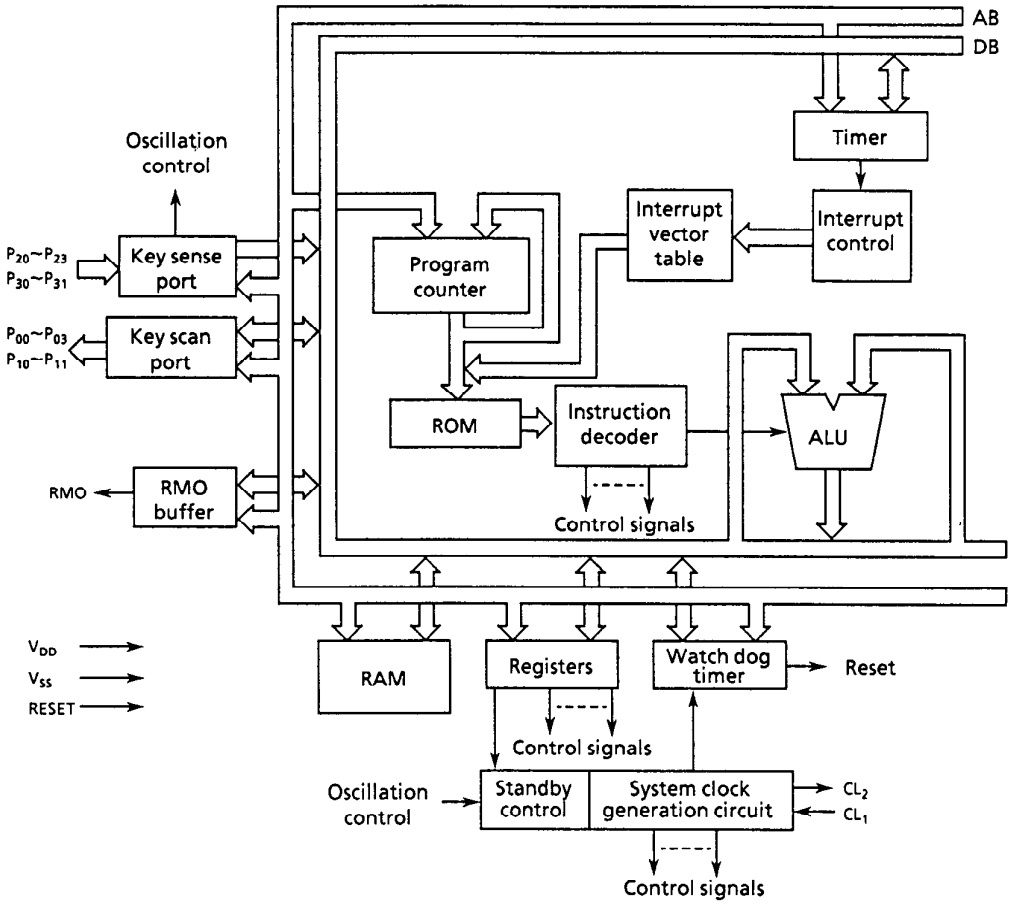

Figure 3

■ Absolute Maximum Ratings

Table 2

Item	Symbol	Conditions	Rating	Unit
Storage temperature	T_{stg}		-40 to + 125	°C
Operating temperature	T_{opr}		-10 to + 70	°C
Power supply voltage	V_{DD}	Ta = 25°C	S-1340AF : -0.3 to + 7.0	V
			S-13L40AF : -0.3 to + 4.0	V
Input voltage	V_{IN}	Ta = 25°C	V_{SS}-0.3 to V_{DD} + 0.3	V
Output voltage	V_{OUT}	Ta = 25°C	V_{SS} to V_{DD}	V
Power dissipation	P_d	Ta = 25°C	300	mW

■ Recommended Operating Conditions

Table 3

(Ta = -10 °C to + 70 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Power supply voltage	V_{DD}	System clock: 500 kHz for S-1340AF	1.8	—	6.0	V
		System clock: 500 kHz for S-13L40AF	1.2	—	3.6	V
Input voltage	V_{IN}		0	—	V_{DD}	V
System clock frequency	f_{sys}	V_{DD} = 1.8 to 6.0 V (S-1340AF) V_{DD} = 1.2 to 3.6 V (S-13L40AF)	200	—	500	KHz

■ DC Characteristics

1. S-1340AF (V_{DD} = 3 V)

Table 4

(Ta = -10 °C to + 70 °C, V_{DD} = 3.0 V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Operating current consumption	I_{CCO}	System clock : 455 KHz	—	0.12	0.25	mA
Standby current consumption	I_{CCS}	At STOP mode	—	0.4	1	μA
High level input voltage	V_{IH}		0.8 × V_{DD}	—	—	V
Low level input voltage	V_{IL}		—	—	0.2 × V_{DD}	V
High level input leakage current	I_{IH}	All input terminals V_{IN} = V_{DD}	—	—	1	μA
Low level input leakage current	I_{IL}	Without pull-up resistor, V_{IN} = V_{SS}	-1	—	—	μA
High level input current	I_{IH}	RESET terminal: When active high V_{IN} = V_{DD}	0.6	2	6	μA
		RESET terminal: When active low V_{IN} = V_{DD}-0.3 V	-9	—	-0.9	μA
Low level input current 1	I_{IL1}	With pull-up resistor, V_{IN} = V_{SS}	-90	-30	-10	μA
Low level input current 2	I_{IL2}	RESET terminal: When active high V_{IN} = V_{SS} + 0.3 V	0.9	—	9	μA
		RESET terminal: When active low V_{IN} = V_{SS}	-6	-2	-0.6	μA
High level output current 1	I_{OH1}	RMO terminal, V_{OUT} = 2.1 V	—	—	-5.0	mA
High level output current 2	I_{OH2}	Output port, V_{OUT} = 2.6 V	—	—	-100	μA
Low level output current 1	I_{OL1}	RMO terminal, V_{OUT} = 0.4 V	250	—	—	μA
Low level output current 2	I_{OL2}	Output port, V_{OUT} = 0.4 V	1.0	—	—	mA
Schmitt hysteresis width	V_{WD}		—	0.7	—	V

2. S-1340AF (V_{DD} = 5 V)

Table 5

(Ta = -10 °C to + 70 °C, V_{DD} = 5 V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Operating current consumption	I_{CCO}	System clock : 455 KHz	—	0.4	0.7	mA
Standby current consumption	I_{CCS}	At STOP mode	—	0.5	5	μA
High level input voltage	V_{IH}		0.8 × V_{DD}	—	—	V
Low level input voltage	V_{IL}		—	—	0.2 × V_{DD}	V
High level input leakage current	I_{IH}	All input terminals V_{IN} = V_{DD}	—	—	1	μA
Low level input leakage current	I_{IL}	Without pull-up resistor, V_{IN} = V_{SS}	-1	—	—	μA
High level input current	I_{IH}	RESET terminal: When active high V_{IN} = V_{DD}	2	7	20	μA
		RESET terminal: When active low V_{IN} = V_{DD}-0.3 V	-13.5	—	-1.5	μA
Low level input current 1	I_{IL1}	With pull-up resistor, V_{IN} = V_{SS}	-270	-90	-30	μA
Low level input current 2	I_{IL2}	RESET terminal: When active high V_{IN} = V_{SS} + 0.3 V	1.5	—	15	μA
		RESET terminal: When active low V_{IN} = V_{SS}	-20	-6.5	-2	μA
High level output current 1	I_{OH1}	RMO terminal, V_{OUT} = 4.1 V	—	—	-8.0	mA
High level output current 2	I_{OH2}	Output port, V_{OUT} = 4.6 V	—	—	-250	μA
Low level output current 1	I_{OL1}	RMO terminal, V_{OUT} = 0.4 V	500	—	—	μA
Low level output current 2	I_{OL2}	Output port, V_{OUT} = 0.4 V	2.0	—	—	mA
Schmitt hysteresis width	V_{WD}		—	1.6	—	V

3. S-13L40AF (V_{DD} = 1.5V)

Table 6

(Ta = -10 °C to +70 °C, V_{DD} = 1.5 V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Operating current consumption	I_{CCO}	System clock : 455 KHz	—	0.05	0.1	mA
Standby current consumption	I_{CCS}	At STOP mode	—	0.5	10.0	μA
High level input voltage	V_{IH}		0.8 × V_{DD}	—	—	V
Low level input voltage	V_{IL}		—	—	0.2 × V_{DD}	V
High level input leakage current	I_{IH}	All input terminals V_{IN} = V_{DD}	—	—	1	μA
Low level input leakage current	I_{IL}	Without pull-up resistor, V_{IN} = V_{SS}	-1	—	—	μA
High level input current	I_{IH}	RESET terminal: When active high V_{IN} = V_{DD}	0.6	2	6	μA
		RESET terminal: When active low V_{IN} = V_{DD}-0.3 V	-9	—	-0.9	μA
Low level input current 1	I_{IL1}	With pull-up resistor, V_{IN} = V_{SS}	-90	-30	-10	μA
Low level input current 2	I_{IL2}	RESET terminal: When active high V_{IN} = V_{SS} + 0.3 V	0.9	—	9	μA
		RESET terminal: When active low V_{IN} = V_{SS}	-6	-2	-0.6	μA
High level output current 1	I_{OH1}	RMO terminal, V_{OUT} = 1.1 V	—	—	-2.0	mA
High level output current 2	I_{OH2}	Output port, V_{OUT} = 1.1 V	—	—	-100	μA
Low level output current 1	I_{OL1}	RMO terminal, V_{OUT} = 0.4 V	200	—	—	μA
Low level output current 2	I_{OL2}	Output port, V_{OUT} = 0.4 V	1.0	—	—	mA
Schmitt hysteresis width	V_{WD}		—	0.2	—	V

4. S-13L40AF (V_{DD} = 3V)

Table 7

(Ta = -10 °C to +70 °C, V_{DD} = 3.0 V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Operating current consumption	I_{CCO}	System clock : 455 KHz	—	0.2	0.4	mA
Standby current consumption	I_{CCS}	At STOP mode	—	0.5	10.0	μA
High level input voltage	V_{IH}		0.8 × V_{DD}	—	—	V
Low level input voltage	V_{IL}		—	—	0.2 × V_{DD}	V
High level input leakage current	I_{IH}	All input terminals V_{IN} = V_{DD}	—	—	1	μA
Low level input leakage current	I_{IL}	Without pull-up resistor, V_{IN} = V_{SS}	-1	—	—	μA
High level input current	I_{IH}	RESET terminal: When active high V_{IN} = V_{DD}	4	12	36	μA
		RESET terminal: When active low V_{IN} = V_{DD}-0.3 V	-20	—	-2.5	μA
Low level input current 1	I_{IL1}	With pull-up resistor, V_{IN} = V_{SS}	-500	-170	-60	μA
Low level input current 2	I_{IL2}	RESET terminal: When active high V_{IN} = V_{SS} + 0.3 V	2.5	—	20	μA
		RESET terminal: When active low V_{IN} = V_{SS}	-35	-12.5	-4	μA
High level output current 1	I_{OH1}	RMO terminal, V_{OUT} = 2.6 V	—	—	-4.0	mA
High level output current 2	I_{OH2}	Output port, V_{OUT} = 2.6 V	—	—	-250	μA
Low level output current 1	I_{OL1}	RMO terminal, V_{OUT} = 0.4 V	400	—	—	μA
Low level output current 2	I_{OL2}	Output port, V_{OUT} = 0.4 V	2.0	—	—	mA
Schmitt hysteresis width	V_{WD}		—	0.7	—	V

■ Instructions

1. 1-byte and 2-byte instructions
   Byte 1 is called "op code", which indicates kinds of instruction.
   Byte 2 is called "operand", which indicates objects of instruction.

2. Ten types of addressing modes

   1) Absolute addressing mode: ABS
   2) Relative addressing mode: REL
   3) Zero page addressing mode: (ZPG)
   4) Register indirect addressing mode: (X)
   5) Post-increment register indirect addressing mode: (X+)
   6) Pre-decrement register indirect addressing mode: (-X)
   7) Register addressing mode: REG
   8) 4-bit immediate addressing mode: IMM4
   9) 8-bit immediate addressing mode: IMM8
   10) Implied addressing mode: IMP

3. Number of instructions

Table 8

	Basic	Including addressing modes
Transfer instruction	13	27
Arithmetic operation instruction	34	47
Logical operation instruction	7	13
Branch instruction	21	21
Shift instruction	2	4
CPU control instruction	2	2
Total	79	114

■ Application Example (S-1340AF)

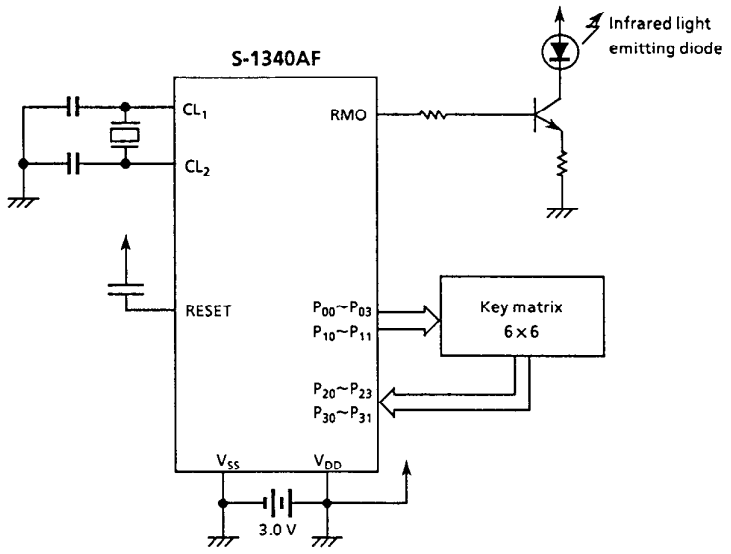

Figure 4